

Thermal Hall effect to probe topological properties

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Summary

- History of the anomalous Hall effect (AHE)
- Berry curvature: Intrinsic AHE Example: Skyrmions lattice in EuPtSi (Berry phase in real space)
- The different thermo-electric coefficients
- The Thermal Hall effect (THE) Examples: Phonon THE (skew scattering, chiral phonons….) Magnon THE
- New perspectives using THE in p-wave superconductors

History of the Anomalous Hall effect

Hall 1879: Ordinary Hall effect of classical physics requires an external magnetic field $\rho_{\rm xv}$ = $R_{\rm o}B$, where R_0 = 1/(*ne*)

Hall 1880: Anomalous Hall effect requires only a magnetisation, ferromagnets display a spontaneous Hall conductivity in the absence of an external magnetic field

The mechanisms responsible for this deflection have been the subject of substantial controversy ever since Hall's experimental work

Several mechanisms are known to be responsible, **spin-orbit interaction** is the main one: **intrinsic** part (material's band structure) and **extrinsic process** (scattering events)

Intrinsic spin-orbit coupling effect are intertwined with the topological properties

3 distinct periods in the understanding of the AHE

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History of the Anomalous Hall effect

Classic Period (1880-1990)

Anomalous Hall effect in transition metals, and on its exact relationship to the magnetisation M .

Empirically : $\rho_{xy} = R_0 B + R_S M$, with the constant R_S referred to as the anomalous Hall coefficient (Pugh & Lippert, 1932).

Frequently $R_s \gg R_0$ (Pugh, et al., 1950) Spontaneous Hall current indeed exists in the absence of a magnetic field, identification of ferromagnetic order.

Contreversy: Role of impurities ((Karplus & Luttinger, 1954 Vs Smit 1955): intrinsic vs extrinsic

(Pugh & Lippert 1932).

Extrinsic process of the AHE

Skew scattering: Spin-up and spin-down electrons are scattered preferentially in different directions. (Smit, 1955; Luttinger & Kohn, 1955; Kohn & Luttinger, 1957; Luttinger, 1958; Luttinger & Kohn, 1958; Adams & Blount, 1959)

 $\rho_{xy} \propto \rho_{xx}$

Side-jump: Spin-up and spin-down electrons undergo a lateral shift in different directions during a scattering process.

(Berger, 1970)

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History of Anomalous Hall effect

Modern Period (1990-2010)

Intrinsic process, scattering-free contribution of Luttinger and Karplus is related to the Berry curvature of Bloch electrons $\rho_{int} \propto \rho_{xx}^2$

Three resistivity regimes have been identified:

- a high mobility regime : skew scattering dominates because τ is large (Majumdar & Berger, 1973)
- a good metal regime : the dominant contribution is independent of τ (Miyasato, et al., 2007), and may be intrinsic or side-jump or both
- a low-mobility regime : conduction occurs primarily by hopping, where the overall picture remains unclear (Nagaosa, et al., 2010).

History of Anomalous Hall effect

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Topological Period (2010-today)

Discovery of many topological materials including topological insulators, Weyl semimetals, transition metal dichalcogenides, and van der Waals heterostructures.

Topological materials have brought with them a new understanding of the AHE Anomalous Hall effect can be quantised in topological insulators and Weyl semimetals

Geometrical phase

Unit vector v(t) lie in the local tangent plane (part of a cone):

Parallel transport on a sphere: $e_3 \times dv = 0$ (Levi-Civita transport)

v does not return to its initial direction when the path is completed.

"geometric" angle $\alpha(C)$ that is path dependent (holonomy)

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```
Mesuring α(C):
v(t) = cos \alpha(t) e_1(t) + sin \alpha(t) e_2(t)W = \theta_3 \times V[v, w, e_3] rotates around the normal by \alpha(t) relative to
[e_1, e_2, e_3]e_3 \times dw = 0
```
Finally dα = $e_1 \cdot de_2 \equiv \omega_{21}$

Berry phase for an electron

Electron constrained to same eigenstate as nuclear coordinate Q is taken around a closed path C will acquire a phase :

 $|\psi\rangle=|n,{\bf Q}\rangle {\rm e}^{-i\chi}$

Parallel transport:

 $\langle n, {\bf Q} | \delta | \psi \rangle = 0$

Berry phase $\chi = -\langle n, \mathbf{Q} | i\delta | n, \mathbf{Q} \rangle$ On completing the path C, the total Berry phase $χ(C)$ is the line integral

$$
\chi(C)=-\oint_C d{\bf Q}\cdot\langle n,{\bf Q}|i\nabla_{\bf Q}|n,{\bf Q}\rangle
$$

Physically, as Q changes, the electronic ket |ψ⟩ stays "parallel" to its initial direction while the local reference ket |n, Q⟩ rotates relative to it.

The Berry phase is the phase angle between them. Vector potential and effective magnetic field representation:

$$
\mathbf{A}(\mathbf{Q}) \, = \, \langle n, \mathbf{Q} | i \nabla_{\mathbf{Q}} | n, \mathbf{Q} \rangle
$$

 $\mathbf{B}(\mathbf{Q}) = \nabla_{\mathbf{Q}} \times \mathbf{A}(\mathbf{Q})$ Berry curvature

Berry phase for Bloch electron

Bloch States :

$$
\psi_{n\mathbf{k}}(\mathbf{r}) = \frac{1}{\sqrt{N}} \mathrm{e}^{i\mathbf{k}\cdot\mathbf{r}} u_{n\mathbf{k}}(\mathbf{r}) = \langle \mathbf{r} | n\mathbf{k} \rangle
$$

band index n and wave vector k

The electron wave vector will acquire a Berry phase

Berry phase

$$
\chi(\mathbf{k}) = -\int_C^{\mathbf{k}} d\mathbf{k}' \cdot \mathbf{X}(\mathbf{k}')
$$

Berry potential vector

 $\mathbf{X}(\mathbf{k})=\int_{cell}d^3r\ u_{n\mathbf{k}}^{*}(\mathbf{r})i\nabla_{\mathbf{k}}u_{n\mathbf{k}}(\mathbf{r})$

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Berry curvature

 $\mathbf{\Omega}(\mathbf{k}) = \nabla_{\mathbf{k}} \times \mathbf{X}(\mathbf{k})$

$$
\hbar \dot{\mathbf{k}} = e\mathbf{E} + e\mathbf{v} \times \mathbf{B}
$$

$$
\hbar \mathbf{v} = \nabla \epsilon_n - e\mathbf{E} \times \mathbf{\Omega}. \quad \text{Anomalous velocity}
$$

Quasiparticles can gain transverse **velocity from non-zero Berry curvature**

Highly similar to the electrons gaining transverse velocity due to the Lorentz force

R. Karplus and J. M. Luttinger, Phys. Rev. **95**, 1154 (1954).

- $J^e = \sigma E \alpha \nabla T$ Fourier's law and Ohm's llaw are entangled through thermoelectric phenomena
- $J^Q = \beta E \kappa \nabla T$ where α is the **thermoelectric conductivity**, β is the **electro-thermal conductivity**. Both quantities are linked through the Kelvin relation: $\beta = \alpha T$.

Boltzman approach:

Charge current

$$
J^{e} = -\int e\vec{v}_{k}\tau\vec{v}_{k} \left(\frac{\partial f^{0}}{\partial \epsilon_{k}}e\vec{E} + \frac{\partial f^{0}}{\partial \epsilon_{k}}\frac{\epsilon_{k} - \mu}{T}(-\nabla T)\right) d\vec{k}
$$

Heat current

$$
J^{Q} = -\int \vec{v}_{k}(\epsilon_{k} - \mu)\tau \vec{v}_{k}(\frac{\partial f^{0}}{\partial \epsilon_{k}}e\vec{E} + \frac{\partial f^{0}}{\partial \epsilon_{k}}\frac{\epsilon_{k} - \mu}{T}(-\vec{\nabla}T))d\vec{k}
$$

Electrical conductivity
$$
\sigma = -e^{2} \int v_{k}^{2} \tau \frac{\partial f^{0}}{\partial \epsilon_{k}}d\vec{k}
$$
 Electrons at the Fermi level

Thermoelectric tensor

$$
\alpha = -ek_B \int v_k^2 \tau \frac{\partial f^0}{\partial \epsilon_k} \frac{\epsilon_k - \mu}{k_B T} d\vec{k}
$$

Electrons just below and above the Fermi level

Thermal conductivity tensor

$$
\int \kappa = -k_B^2 T \int v_k^2 \tau \frac{\partial f^0}{\partial \epsilon_k} (\frac{\epsilon_k - \mu}{k_B T})^2 d\vec{k}
$$

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$$
\sigma \approx e^2 \cdot \frac{1}{3} v_k^2 \tau(k) N(\epsilon) = \frac{n e^2 \tau}{m}
$$

$$
\kappa \approx \frac{\pi^2}{3} k_B^2 T \cdot \frac{1}{3} v_k^2 \tau(k) N(\epsilon) = \frac{1}{3} C v l
$$

Wiedemann-Franz law

$$
\frac{\kappa}{\sigma} = \frac{\pi^2}{3} \frac{k_B^2}{e^2} T = L_0 T
$$

Lorentz number $L_0 = 2.4453 \times 10^{-8} W \Omega K^{-2}$

Sommerfeld expansion

Only true in the zero temperature limit: elastic scattering is the dominant one. At finite temperature, inelastic scattering give rise to the deviation of the WF law

Vertical (small-angle) scattering efficiently decays heat current but not charge current

Anomalous Hall effect

$$
\mathbf{J} = e \sum_{\mathbf{k},s} \mathbf{v}_{\mathbf{k}} [f_{\mathbf{k}}^0 + g_{\mathbf{k}}],
$$
 the unperturbed fonction $f_{\mathbf{k}}^0$
+

$$
\mathbf{J}_H = \frac{e^2}{\hbar} \mathbf{E} \times \sum_{\mathbf{k},\mathbf{s}} \Omega(\mathbf{k}) f_{\mathbf{k}}^0
$$

Anomalous Hall effect will come from summing up all the **velocities from all the occupied states**:

$$
\sigma_{xy} = \frac{e^2}{\hbar} \int \frac{d^d k}{(2\pi)^d} f(\epsilon_k) \Omega_{k_x, k_y}
$$

Fermi sea

 $\sigma_{xy} = \frac{\rho_{xy}}{\rho_{xx}^2 + \rho_{xy}^2}$

Thus even in the absence of a magnetic field you can get a Hall effect

$$
\rho_{xy} = \sigma_{xy} \rho^2
$$
 is the quantity that is measured $\rho \sim (n\tau)^{-1}$

ρ_{xy} Intrinsic Scales like ρ^2 .

By contrast, skew-scattering theories predict
$$
\sigma_{xy} \sim (n\tau)
$$
 that

 p_{xy} SKEW IS linear in p .

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Symmetries breaking

What materials have non-zero Ω and hence a significant Anomalous Hall effect?

```
\Omega = 0 if the system has both time reversal and inversion symmetry.
Time reversal takes v \rightarrow -v, E \rightarrow E and k \rightarrow -k.
\Omega(-k) = -\Omega(k)
```

```
Inversion symmetry takes v \rightarrow -v, E \rightarrow -E and k \rightarrow -k.
\Omega(-k) = \Omega(k).
```
The only consistent way to have both symmetry is to have $\Omega = 0$.

Time reversal symmetry is broken in ferromagnets, antiferromagnets, Weyl Semi Metals

Ferromagnets : M breaks time-reversal symmetry for the spins.

This symmetry-breaking communicated to the charge currents via spin-orbit coupling.

 J_H = 2ne2 λ E × S that is linear in the carrier density n and M, independent of τ

Spinel Ferromagnet

N. P. Ong *et al.* Science (2004)

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Skyrmions in solid state physics

Skyrmion:• magnetic spin structure in which the center magnetization is opposite to its boundary

- non-trivial real space topology of nano-whirls
- theoretical predictions already in late 80th (Bogdanov and Yablonskii, JETP 1989)
- discovered in bulk materials MnSi (2009)

where to look for skyrmions

systems with broken inversion symmetry (chiral systems)

Muhlbauer et Al. , Science, 323, 915-919 (2009)

• exchange interaction with spin orbit

• Dzyaloshinsky – Moriya interaction

$$
H_{\text{ex}} = -\frac{1}{2} \sum_{ij} J_{i,j} \, \mathbf{s}_i \cdot \mathbf{s}_j.
$$
\n
$$
H_{DM} = \sum_{ij} \mathbf{D}_{ij} \cdot \mathbf{S}_i \times \mathbf{S}_j
$$

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 $\frac{1}{2}$ of the chance of the contract of the contract of helical modulation period: $\lambda = 2\pi/|q_H|$ (180 Å)

$$
m(r) = \cos(q_H \cdot r) \cdot n_1 + \sin(q_H \cdot r) \cdot n_2
$$

conical modulation under magnetic field

- crystal field anisotropy
- magnetic frustration
- dipole dipole interaction stabilizes large objects

$$
H_{\mathrm{dd},ij} = -\frac{\mu_0}{4\pi} \left(3 \frac{(\mathbf{s}_i \cdot \mathbf{r}_{ij})(\mathbf{s}_j \cdot \mathbf{r}_{ij})}{r_{ij}^5} - \frac{\mathbf{s}_i \cdot \mathbf{s}_j}{r_{ij}^3} \right).
$$

EuPtSi

- Rare-earth *4f 7*
- Divalent Eu^{2+} ($L = 0$, $S = J = 7/2$)
- Large localized moments
- Cubic chiral structure of Ullmannite-type (NiSbS type) space group 2,3 (No. 198) *T*4 (like MnSi)
- crystallographic point group 23 (*T* in Schoenflies notation)
- **lack of inversion and mirror symmetry**
- three-fold rotation axis along [111]
- two-fold rotation axis along main axes [100]
- trillium lattice \rightarrow magnetic frustration

EuPtSi

A-phase in EuPtSi *H* || [111] discovered in 2018 (Kakihana et *al.*)

- From 0.75 to 1.4 T and 0.45 to 4 K \rightarrow much larger than in MnSi
- topological Hall effect (THE)
- triple-*q* order indicating a Skyrmion Lattice
- small skyrmion size \rightarrow 10 times smaller than in MnSi

 $q_1 = (-0.29, 0.09, 0.20)$ $q_2 = (-0.20, 0.29, -0.09)$ $q_3 = (0.09, 0.20, -0.29)$ **20**
20

$$
\lambda = \frac{2\pi}{|q|} = 18 \,\text{\AA}
$$

H || [111] – Topological Hall effect

Topological Hall effect in the A-phase

explained by skew-scattering

H || [111] – Topological Hall effect

Topological Hall effect induced by the spin texture of SkL :

- conduction electrons coupled to non-coplanar spin textures acquire a Berry phase in real space \rightarrow emergent magnetic field B_{em} opposing the applied field
- similar to Lorentz force on the motion of the electron

$$
B_{em} = -\frac{h}{e} \left(\frac{\sqrt{3}}{2 \lambda^2}\right) \approx -1105 \text{ T} \qquad \lambda = 18 \text{ Å}
$$

 $\rho_H^{THE} \propto P R_0 B_{em}$

- $P = \frac{\mu_{sp}}{n} \approx 0.1$ Polarisation P arises from the majority and minority- μ_{sat} spin carriers, which collect Berry phases of opposite sign.
- *R0* the ordinary Hall constant

MnSi: $B_{em} \approx -13.15$ T $\rho_H^{THE} \approx 5 \text{ n}\Omega \cdot \text{cm}$

EuPtSi:

small skyrmion size \rightarrow high skyrmion density \rightarrow large emergent field \rightarrow large THE $\rho_H^{THE} \approx 0.1 \mu \Omega \cdot \text{cm}$

H || [111] – Field dependence of resistivity

- large enhancement of *ρ* in the SkL phase: scattering of conduction electrons on the dense SkL
- rapid decrease of $\Delta \rho_{max}$ below 0.7 K
- Strong hysteresis below 1 K in

From Anomalous Hall effect to Thermal Hall effect

Berry curvature is intricate to the wavefunctions of the energy bands, not with particular quasiparticles:

Electrons, as well as charge-neutral excitations such as magnons and phonons

For magnons and phonons: a thermal Hall effect (THE)

For electrons : THE is simply caused by Lorentz force, just the same as the Hall effect

THE occurs even in insulators and that is the attractive and interesting point

It is particularly helpful in unveiling the exotic properties of quantum materials

Thermal Hall Effect Measurement

Thermal conductivity-resistivity

$$
\kappa_{xx} = \frac{W_{xx}}{W_{xx}^2 + W_{xy}^2}
$$
\n
$$
W_{xx} = \frac{-\nabla T_x}{J^Q}
$$
\n
$$
\kappa_{xy} = \frac{-W_{xy}}{W_{xx}^2 + W_{xy}^2}
$$
\n
$$
W_{xy} = \frac{-\nabla T_y}{J^Q}.
$$

In most cases, $W_{xx} \gg W_{xy}$, so the $\kappa_{xx} \approx -\frac{J^Q}{\nabla T_x}$ and $\kappa_{xy} \approx -\kappa_{xx} \frac{\nabla T_y}{\nabla T_x}$

$$
\mathcal{L} \times \mathcal{L}
$$

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INTRINSIC THE

For electrons:

$$
\kappa_{\mathrm{H}} = -\frac{1}{e^2\hslash T} \int (\epsilon - \mu)^2 \frac{\partial f(\epsilon)}{\partial \epsilon} \sigma(\epsilon) d\epsilon
$$

$$
\sigma(\epsilon) = -\frac{e^2}{\hslash V} \sum_{(\epsilon_n q) \leq \epsilon} \Omega_n(q) \quad \text{Intrinsic AHE}
$$

For phonons:

$$
\kappa_{\mathrm{H}} = \frac{1}{2V\hbar T} \sum_{\boldsymbol{q},n=1,2nd} \left[\int_{\varepsilon_n(\boldsymbol{q})}^{\infty} \epsilon^2 \frac{\partial f}{\partial \epsilon} d\epsilon \right] \Omega_n(\boldsymbol{q})
$$

Fermi-Dirac distribution $f(\epsilon) = 1/(\frac{e^{(\epsilon-\mu)/(k_B T)}}{T} + 1)$

Bose Einstein distribution $f(\epsilon) = 1/(e^{\epsilon/(k_B T)} - 1).$

The corresponding anomalous velocity of the phonon is proportional to $\Omega \times \nabla T$

For magnons :

$$
\kappa^{xy}=-\frac{k_{\rm B}^2T}{\hbar V}\sum_{n,k}c_2(\rho_n)\Omega_{n,z}(k). \qquad \rho(\varepsilon)=(e^{(\varepsilon-\mu)/k_{\rm B}T}-1)^{-1},
$$

Examples of THE

Examples of THE

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Evolution of the experimentally observed THE

Note that although the κ_{xy} in these materials differs in three orders of amplitude, while the ratio of K_{xy} and κ_{xx} which is called thermal Hall angle are not so different around few per thousand

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Thermal conductivity of phonons

Similarly to the electronic one:

$$
\kappa_{ph}=\frac{1}{3}\int_0^{\frac{\theta_D}{T}}C(x)v l(x)dx
$$

Ballistic: mean-free-path I of the phonons becomes comparable with the sample size **T**³ thermal conductivity

Ziman: Few Umklapp process in phonon-phonon scattering $\tau \propto T^{-1} e^{\theta_D/T}$

 $\kappa \propto e^{\theta_D/aT}$.

Diffusive: Dominance of Umklapp scattering. $\tau \propto T^{-1}$

T⁻¹ **thermal conductivity**

THERMAL HALL EFFECT OF PHONONS :

Extrinsic THE: Tb₃Ga₅O₁₂

First discovered in paramagnetic insulator $Tb_3Ga_5O_{12}$: skew scattering of phonons Spin-phonon interaction

C. Strohm *et al.*, Phys. Rev. Lett. 95, 155901(2006). A.V. Inyushkin et al., JETP Lett. 86, 379 (2007).

THERMAL HALL EFFECT OF PHONONS

SrTiO₃ : extrinsic κ_{xy} related to skew scattering or intrinsic κ_{xy} linked to ferroelectric fluctuations (Berry phase)?

The intrinsic κ_{xy} is still orders of magnitude smaller than the observed effect, and the extrinsic κ_{xy} proportional to the phonon mean-free path appears likely to explain the observations

LI X, FAUQUÉ B, ZHU Z, BEHNIA K, . Phys. Rev. Le2., **124,** 105901 (2020).

CONTRACTOR

How to get the origin of the THE

1/ Mesure all the thermal, thermo-electric and electric coefficients

 $\vec{J}^e = \overline{\sigma'} \vec{E} - \overline{\alpha} \vec{\nabla} T$

 $\vec{J}^Q = \overline{\alpha} T \vec{E} - \overline{\kappa'} \vec{\nabla} T$

K_{xγ}

In the case of a thermal experiment where

 $\vec{JQ} = (\overline{\alpha}\,\overline{\rho}\,\overline{\alpha}\,T - \overline{\kappa'})\vec{\nabla T}$

 $\vec{JQ} \neq \vec{0}, \vec{J}^e = \vec{0}$

κxy and κʹxy are significantly different

Consequence of a large Hall angle ($\sigma_{xx} \approx \sigma_{xy}$), large thermoelectric power and Nernst effect

How to get the origin of the THE

2/ Wiedemann-Franz law to estimate the electronic contribution

$$
\kappa^e_{xy}=L_0\sigma_{xy}T
$$

$$
\varDelta\kappa_{xy}=\kappa_{xy}-\kappa_{xy}^{ph}-\kappa_{xy}^e
$$

LI X, FAUQUÉ B, ZHU Z, BEHNIA K . Phys. Rev. Le2., **124,** 105901 (2020).

Thermal Hall Effect of Phonons

Drag on phonons by the electric current

$$
\kappa_{xy}(drag)=-\alpha_{xy}\frac{m^*v_s^2}{e}f\frac{\tau_p}{\tau_e}
$$

The component of thermal Hall conductivity generated by mutual drag between electrons and phonons is proportional to the product of α_{xy} , the ratio of phonon and electron τ_e scattering times τ_p and the efficiency of momentum transfer between the two baths

Peltier phonon drag

Thermal Hall phonon drag

Magnon Thermal Hall Effect

The heat carriers can only be phonons or magnons $\textsf{Lu}_2\textsf{V}_2\textsf{O}_7$: Insulating collinear ferromagnet T_c =70 K

Population of magnons decreases as the magnetic field increases

Y. Onose, et al., Science 329, 297 (2010).

Materials with controversial origins of THE

RuCl3Quantum spin liquid

3 types of Heat carriers:

1/ Majorana fermions predicted to occur in Kitaev quantum spin liquid

 $\kappa_{xy}^{\text{2D}}/T = c(\pi/6) \left(k_{\text{B}}^2/\hbar\right)$

CZAJKA P et al. Nat. Phys., 17, 915 (2021) YOKOI et al. Science 373 568 (2021)

Observation of a plateau in the THE???

2/ Phononic skew scattering THE HENTRICH et al. Phys. Rev. Lett., 120: 117204 (2018) 3/ Electronic THE: quantum oscillation in k_{xx}

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Materials with controversial origins of THE

Cuprate High-Temperature Superconductors

Chiral phonons ?

Without doping : Mott insulators

Overdoped regime : Fermi liquid

Intermediate regime : the pseudogap phase many unusual

phenomena

Materials with Controversial Origins of THE

Cuprate High-Temperature Superconductors

³⁹ Grisonnanche et al. Nature 571, 376 (2019)

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Materials with Controversial Origins of THE

Cuprate High-Temperature Superconductors

1/ electrons ? since the parent compound, a Mott insulator generate large signals, NO.

2/ magnons ? as K_{xy} remains even without static magnetism, NO.

3/ phonons :Isotropy of the thermal Hall conductivity : YES

Phonons become chiral in the pseudo gap phase

Many-body scattering of phonons by collective modes: a consequence of non- Gaussian correlation (skew scattering)

Mangeolle, Phys. Rev. X **12**, 041031 (2022)

40 Grisonnanche et al. Nature 571, 376 (2019)

A superconductor is chiral (spin-triplet) when it breaks time-reversal symmetry (TRS) due to its orbital degrees of freedom

First signature : A small internal magnetic field below the critical superconducting temperature, arising from the finite orbital momentum, detected by muon spectroscopy, Kerr effect, knight shift in NMR measurements

Alternative signature :

Anomalous bulk thermal Hall effect is predicted in chiral *p*-wave superconductors

Quantized thermal Hall at zero field from the presence of edge heat currents similar to the edge charge currents of the integer quantum Hall effect

$$
\kappa_{x,y}=\frac{\pi k_B^2 T}{12\hbar}=\frac{1}{4}{\cal L}_0G_0T
$$

New perspective THE in p-wave superconductor

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Summary

- The thermal Hall effect, plays and will continue to play a major role in characterizing insulating quantum materials.
- Both phonons and pure spin excitations can contribute to k_{xy} , where the underlying mechanisms vary, but a common feature is that heat carriers are subject to chirality in one way or another.
- Phonons can be conferred chirality through various extrinsic and intrinsic mechanisms. The extrinsic mechanisms are related to the scattering by rare-earth impurities and by structural domain boundaries, while the intrinsic mechanisms include the Berry curvature and coupling of phonons to spins.
- Besides phonons, spin excitations such as magnons also play a critical role in the thermal Hall effect in insulating magnets. Dzyaloshinskii–Moriya interaction is a dominant mechanism of the magnon thermal Hall effect.
- Anomalous bulk thermal Hall effect is predicted in chiral *p*-wave superconductors

With electrical field:

$$
\frac{d f_k(\vec r)}{d t}\big|_{\vec E} = \frac{\partial f_k(\vec r)}{\partial \epsilon_k} \frac{\partial \epsilon_k}{\partial \vec k} \frac{\partial \vec k}{\partial t} = \frac{\partial f_k(\vec r)}{\partial \epsilon_k} \hbar \vec v_k \frac{e \vec E}{\hbar} \approx \frac{\partial f^0}{\partial \epsilon_k} \vec v_k e \vec E
$$

Group velocity $\vec{v}_k = \frac{1}{\hbar} \frac{\partial \epsilon_k}{\partial \vec{k}}$

With a thermal gradient:

$$
\frac{df_k(\vec{r})}{dt}|_{\vec{\nabla}T} = \frac{\partial f_k(\vec{r})}{\partial T} \frac{\partial T}{\partial \vec{r}} \frac{\partial \vec{r}}{\partial t} = \frac{\partial f_k(\vec{r})}{\partial T} \vec{v}_k \vec{\nabla} T \approx \frac{\partial f^0}{\partial T} \vec{v}_k \vec{\nabla} T
$$

With thermal gradient and electrical field:

$$
f_k(\vec{r}) = f^0 - \tau \vec{v}_k \left(\frac{\partial f^0}{\partial \epsilon_k} e \vec{E} + \frac{\partial f^0}{\partial \epsilon_k} \frac{\epsilon_k - \mu}{T} \vec{\nabla} T \right) \qquad \frac{\partial f^0}{\partial T} = -\frac{\partial f^0}{\partial \epsilon_k} \frac{\epsilon_k - \mu}{T}
$$

Perturbated distribution function under electrical field and thermal gradient

Anomalous Hall effect

Kubo formula:

 $\sigma_{xy}(\omega) = i \sum_{k,n,m} \frac{\langle mk|J_x|nk \rangle \langle nk|J_y|mk \rangle}{\varepsilon_n(k) - \varepsilon_m(k)}$ $\times \frac{f(\varepsilon_n(k)) - f(\varepsilon_m(k))}{\omega + i\delta + \varepsilon_m(k) - \varepsilon_n(k)},$ ÷

$$
\langle nk|J_{\mu}|mk\rangle = (\varepsilon_m(k) - \varepsilon_n(k))\langle nk|\partial/\partial k_{\mu}|mk\rangle
$$

Overlap integral of the two Bloch wave functions at neghboring points in k-space

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Transverse transport in magnetic field

$$
\hbar \frac{df_k(\vec{r})}{dt} \mid_{\vec{B}} = \hbar \frac{df_k(\vec{r})}{d\vec{k}} \frac{d\vec{k}}{dt} = e(\vec{v_k} \times \vec{B}) \frac{df_k(\vec{r})}{d\vec{k}} \qquad \text{The distribution function in the presence of a magnetic field}
$$
\n
$$
f_k(\vec{r}) = f_k^0(\vec{r}) + g_k(\vec{r}) \qquad e(\vec{v_k} \times \vec{B}) \frac{df_k^0(\vec{r})}{d\vec{k}} = e(\vec{v_k} \times \vec{B}) \cdot \hbar \vec{v_k} \frac{df_k^0(\vec{r})}{d\epsilon_k} = 0
$$
\n(Only true if Landau quantization is negligible)

With thermal gradient, electrical field and magnetic field:

$$
\frac{df_k(\vec{r})}{dt} = \frac{e}{\hbar}(\vec{v_k} \times \vec{B})\frac{\partial g_k(\vec{r})}{\partial \vec{k}} + \frac{\partial f^0}{\partial \epsilon_k}\vec{v_k}e\vec{E} + \frac{\partial f^0}{\partial T}\vec{v_k}\vec{\nabla}T = -\frac{g_k(\vec{r})}{\tau}
$$

$$
g_k(\vec{r}) = -\mu(\vec{v_k} \times \vec{B}) \frac{\partial g_k(\vec{r})}{\partial \vec{v}} - e\tau \frac{\partial f^0}{\partial \epsilon_k} \vec{v_k} \vec{E} - \tau \frac{\partial f^0}{\partial T} \vec{v_k} \vec{\nabla} T
$$

$$
= -\vec{v_k} \cdot (\mu \vec{B} \times \frac{\partial g_k(\vec{r})}{\partial \vec{v}} + e\tau \frac{\partial f^0}{\partial \epsilon_k} \vec{E} + \tau \frac{\partial f^0}{\partial T} \vec{\nabla} T)
$$

With the mobility:

$$
\mu = \tfrac{e\tau}{m} = \tfrac{e\tau}{\hbar} \tfrac{\partial v}{\partial k}
$$

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